



CofC

PATENT  
Attorney Docket No.: SAM-0461  
Customer No.: 29344

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Chang-bong Oh, *et al.*  
Serial No.: 10/649,222  
Filing Date: August 26, 2003  
Patent Number: 6,900,503 B2  
Issue Date: May 31, 2005  
Group Art Unit: 2815  
Examiner: Jackson Jr., Jerome  
Title: SRAM FORMED ON SOI SUBSTRATE

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

7/21/05  
Date

  
Chelsey Davis

Certificate of Corrections Branch  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

TRANSMITTAL LETTER

Certificate  
JUL 28 2005  
of Correction

Sir:


Enclosed herewith for filing in the above-identified patent application please find the following:

1. Petition for Certificate of Correction under 37 C.F.R. § 1.322;
2. Certificate of Correction; and
3. Return Postcard

In connection with the foregoing matter, please charge any additional fees which may be due, or credit any overpayment, to Deposit Account Number 50-1798. A duplicate copy of this letter is provided for this purpose.

Respectfully submitted,

Date: July 21, 2005  
Mills & Onello, LLP  
Eleven Beacon Street, Suite 605  
Boston, MA 02108  
Telephone: (617) 994-4900  
Facsimile: (617) 742-7774  
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Anthony P. Onello, Jr.  
Registration Number 38,572  
Attorney for Applicants

JUL 28 2005



PATENT  
Attorney Docket No.: SAM-0461

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Date

Chelsey Davis

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Certificate of Corrections Branch  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

PETITION FOR CERTIFICATE OF CORRECTION UNDER 37 C.F.R. § 1.322

Sir:

The patentee of the above-identified patent, through its attorney, hereby petitions for issuance of a Certificate of Correction in the above-identified patent. A certificate is required to correct the errors in the claims as follows:

In Column 9, Claim 7, Line 18 delete "dram" and insert --drain--.

JUL 28 2005

Applicant(s): Chang-bong Oh, *et al.*  
Serial No.: 10/649,222

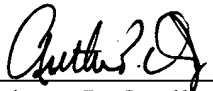
In Column 10, Claim 17, Line 41 after "acute" insert --angle with a portion of each of the first and second active areas where the NMOS transistors are--.

It is respectfully requested that a Certificate of Correction be issued to correct the errors in the claims.

The correction is not believed to involve such change as would constitute new matter or require examination. Since the error is the fault of the United States Patent and Trademark Office, it is believed that no fee is due.

Respectfully submitted,

Date: July 21, 2005  
Mills & Onello, LLP  
Eleven Beacon Street, Suite 605  
Boston, MA 02108  
Telephone: (617) 994-4900  
Facsimile: (617) 742-7774  
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Anthony P. Onello, Jr.  
Registration Number 38,572  
Attorney for Applicant

JUL 28 2005

**UNITED STATES PATENT AND TRADEMARK OFFICE**

**CERTIFICATE OF CORRECTION**

**PATENT NO.:** 6,900,503 B2

**DATED:** May 31, 2005

**INVENTOR(S):** Chang-bong Oh, *et al.*

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In Column 9, Claim 7, Line 18 delete "dram" and insert --drain--.

In Column 10, Claim 17, Line 41 after "acute" insert --angle with a portion of each of the first and second active areas where the NMOS transistors are--.

**MAILING ADDRESS OF SENDER:**

Anthony P. Onello, Jr.  
Mills & Onello LLP  
Eleven Beacon Street, Suite 605  
Boston, MA 02108

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**PATENT NO.:** 6,900,503 B2

**JUL 28 2005**